# MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PLED

# ESD05V14T-LC-MS

# **Product specification**





#### FEATURES

- Ultra low leakage: nA level
- Operating voltage: 5V
- Low clamping voltage
- Complies with following standards:
- IEC 61000-4-2 (ESD) immunity test Air

discharge: ± 15kV

- Contact discharge: ±8kV
- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning) 3A

(8/20µs) RoHS Compliant

#### MACHANICAL DATA

- SOT-143 package
- Flammability Rating: UL 94V-0
- Packaging: Tape and Reel
- High temperature soldering guaranteed: 260°C/10s
- Reel size: 7 inch

## APPLICATIONS

- USB 2.0 power and data line
- Set-top box and digital TV
- Digitalvideointerface (DVI)
- Notebook Computers
- SIM Ports
- 10/ 100 Ethernet

#### **Reference News**

PACKAGE OUTLINE	PIN CONFIGURATION	Marking
		R05
SOT-143		



#### **ABSOLUTE MAXIMUM RATING**

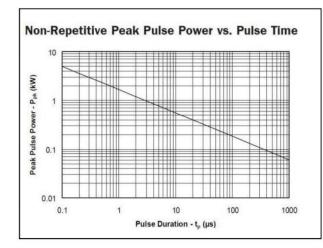
Symbol	Parameter	Value	Units
Ррр	Peak Pulse Power (8/20µs)	150	W
Vesd	ESD per IEC 61000-4-2 (Air)	±15	Kv
Vesd	ESD per IEC 61000-4-2 (Contact)	±8	Kv
TJ	Operating Temperature Range	-55 to + 125	°C
Тѕтј	Storage Temperature Range	-55 to + 150	C

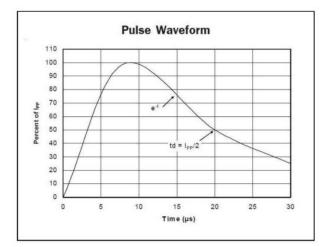
# ELECTRICAL CHARACTERISTICS (Tamb=25 °C)

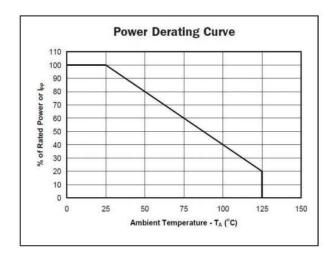
Symbol	Parameter	Test Condition	Min	Тур	Мах	Units
VRWM	Reverse Working Voltage				5.0	V
VBR	Reverse Breakdown Voltage	IT = 1mA	6.0			V
IR	Reverse Leakage Current	VRWM = 5V			100	nA
VC	Clamping Voltage	IPP = 1A, tp = 8/20µs			9.8	V
		IPP = 5 A, tp = 8/20µs			15	V
Сј	Junction Capacitance	VR = 0V, f = 1MHz		1.2		pF

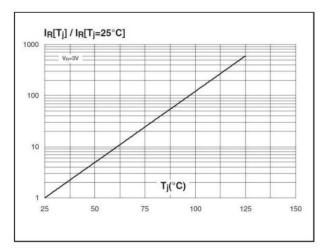


## **ELECTRICAL CHARACTERISTICS CURVE**



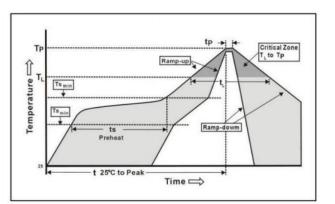






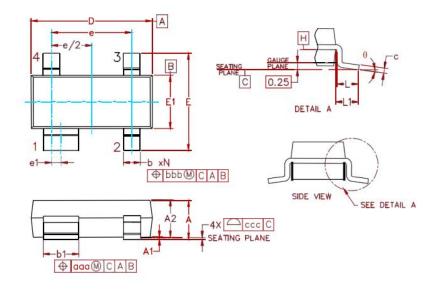
## Soldering Parameters

Reflow Condition		Fb – Free assembly	
Pre Heat	-Temperature Min (T <sub>s(Min)</sub> )	150°C	
	- Temperature Max (T <sub>s(Max)</sub> )	200°C	
	-Time (Min to max) (t <sub>s</sub> )	60 - 180 secs	
Average r (T <sub>L</sub> ) to pea	amp up rate (Liquidus) Temp Ik	3°C/second Max	
T <sub>S (Max)</sub> to T	- Ramp-up Rate	3°C/second Max	
Reflow	-Temperature (T <sub>1</sub> ) (Liquidus)	217°C	
	- Temperature (t <sub>i</sub> )	60 – 150 seconds	
Peak Temperature (T <sub>p</sub> )		250+0/-5 °C	
Time within 5°C of actual peak Temperature (t <sub>p</sub> )		20 – 40 seconds	
Ramp-dowm Rate		6°C/second Max	
Time 25°C to peak Temperature (T <sub>p</sub> )		8 minutes Max.	
Do not exceed		260°C	





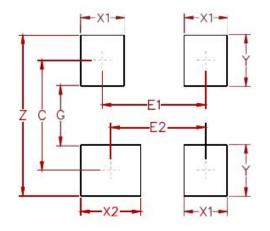
#### PACKAGE MECHANICAL DATA



	Inches		Millimeters			
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max
Α	0.031	•	0.048	0.80		1.22
A1	0.000		0.008	0.013		0.15
A2	0.020	0.035	0.042	0.75	0.90	1.07
b	0.011		0.020	0.30		0.51
b1	0.029		0.037	0.76		0.94
С	0.003		0.008	0.08		0.20
D	0.110	0.114	0.120	2.80	2.90	3.04
E	0.082	0.093	0.104	2.10	2.37	2.64
E1	0.047	0.051	0.055	1.20	1.30	1.40
е	0.075		1.92 BSC			
e1	0.008		0.20 BSC			
L	0.015	0.020	0.024	0.40	0.50	0.60
L1	(0.021)				(0.54)	
N	4			4		
θ	0°	-	8°	0°	Υ.	8°
aaa	0.006			-	0.15	
bbb	0.008		0.20			
ccc	0.004				0.10	



Suggested Pad Layout



#### **REEL SPECIFICATION**

P/N	PKG	QTY
ESD05V14T-LC-MS	SOT-143	3000



#### **Attention**

Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.

MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all MSKSEMI Semiconductor products described or contained herein.

Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

MSKSEMI Semiconductor. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with someprobability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits anderror prevention circuits for safedesign, redundant design, and structural design.

■ In the event that any or all MSKSEMI Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from theauthorities concerned in accordance with the above law.

■ No part of this publication may be reproduced or transmitted in any form or by any means, electronic or

mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.

Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements intellectual property rights or other rights of third parties.

Any and all information described or contained herein are subject to change without notice due to

product/technology improvement, etc. Whendesigning equipment, referto the "Delivery Specification" for the MSKSEMI Semiconductor productthat you intend to use.